

SSAC18

Solid State AC Controller(Anti-Parallel Thyristor-Thyristor Modules)

| Symbol | Test Conditions | Characteristic Values | Unit |
|--------------------|--|-----------------------|-----------|
| I_{RRM}, I_{DRM} | $T_{VJ}=T_{VJM}; V_R=V_{RRM}; V_D=V_{DRM}$ | 3 | mA |
| V_T, V_F | $I_T, I_F=80A; T_{VJ}=25^{\circ}C$ | 2.05 | V |
| V_{TO} | For power-loss calculations only ($T_{VJ}=125^{\circ}C$) | 0.85 | V |
| r_T | | 18 | $m\Omega$ |
| V_{GT} | $V_D=6V;$ $T_{VJ}=25^{\circ}C$ $T_{VJ}=-40^{\circ}C$ | 1.5 1.6 | V |
| I_{GT} | $V_D=6V;$ $T_{VJ}=25^{\circ}C$ $T_{VJ}=-40^{\circ}C$ | 100 200 | mA |
| V_{GD} | $T_{VJ}=T_{VJM};$ $V_D=2/3V_{DRM}$ | 0.2 | V |
| I_{GD} | | 10 | mA |
| I_L | $T_{VJ}=25^{\circ}C; t_p=10\mu s; V_D=6V$ $I_G=0.45A; di_G/dt=0.45A/\mu s$ | 450 | mA |
| I_H | $T_{VJ}=25^{\circ}C; V_D=6V; R_{GK}=\infty$ | 200 | mA |
| t_{gd} | $T_{VJ}=25^{\circ}C; V_D=1/2V_{DRM}$ $I_G=0.45A; di_G/dt=0.45A/\mu s$ | 2 | μs |
| t_q | $T_{VJ}=T_{VJM}; I_T=20A; t_p=200\mu s; -di/dt=10A/\mu s$ $V_R=100V; dv/dt=20V/\mu s; V_D=2/3V_{DRM}$ | 150 | μs |
| Q_S | $T_{VJ}=T_{VJM}; I_T, I_F=25A; -di/dt=0.64A/\mu s$ | 50 | μC |
| I_{RM} | | 6 | A |
| R_{thJC} | per thyristor/diode; DC current per module | 1.3 0.65 | K/W |
| R_{thJK} | per thyristor/diode; DC current per module | 1.5 0.75 | K/W |
| d_s | Creeping distance on surface | 12.7 | mm |
| d_A | Strike distance through air | 9.6 | mm |
| a | Maximum allowable acceleration | 50 | m/s^2 |

FEATURES

- * International standard package
- * Copper Base Plate with Inter-DCB
- * Planar passivated chips
- * Isolation voltage 3600 V~

APPLICATIONS

- * DC motor control
- * Softstart AC motor controller
- * Light, heat and temperature control

ADVANTAGES

- * Space and weight savings
- * Simple mounting with two screws
- * Improved temperature and power cycling
- * Reduced protection circuits

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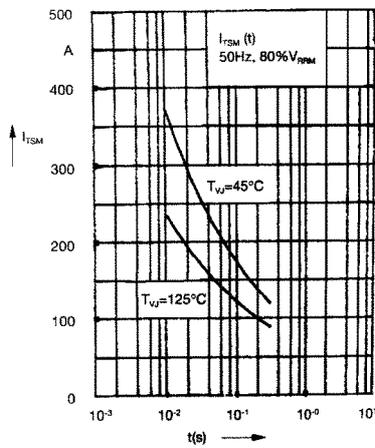


Fig. 1 Surge overload current
 I_{TSM} : Crest value, t : duration

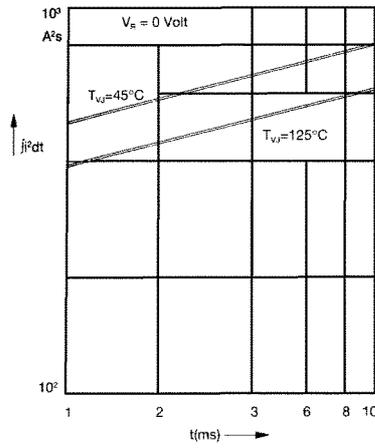


Fig. 2 $\int i^2 dt$ versus time (1-10 ms)

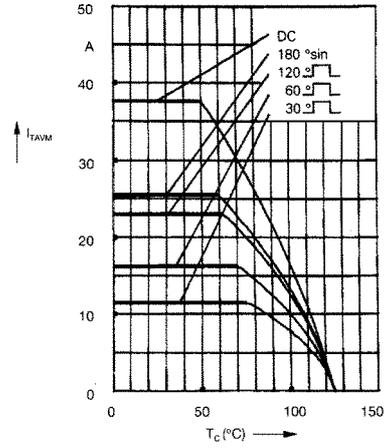


Fig. 2a Maximum forward current at case temperature

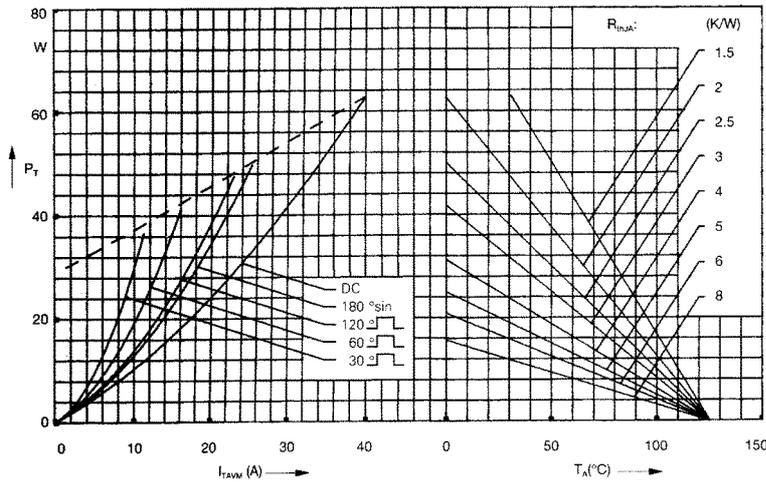


Fig. 3 Power dissipation versus on-state current and ambient temperature (per thyristor)

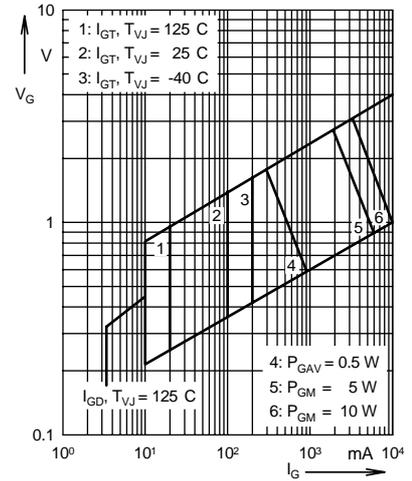


Fig. 4 Gate trigger characteristics

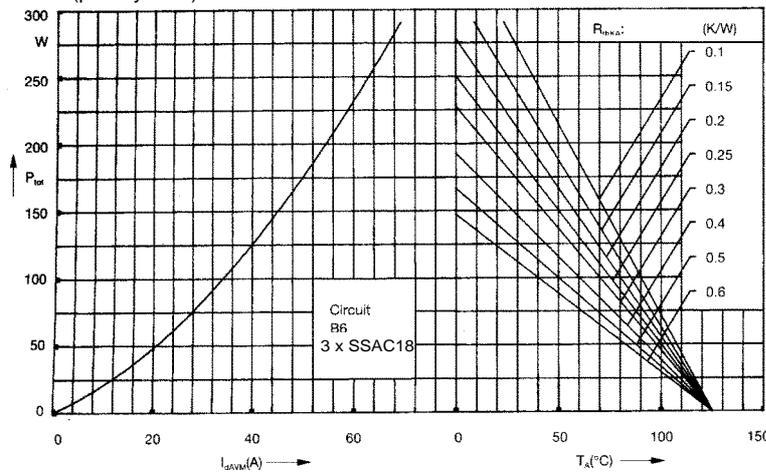


Fig. 5 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

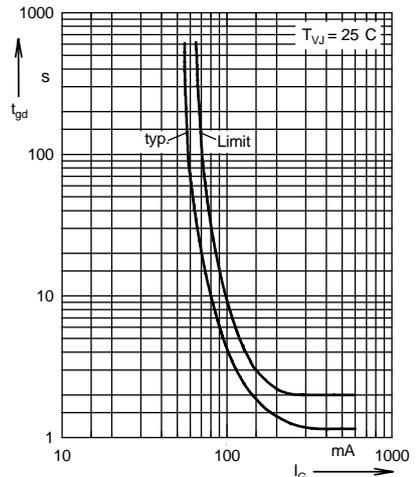


Fig. 6 Gate trigger delay time

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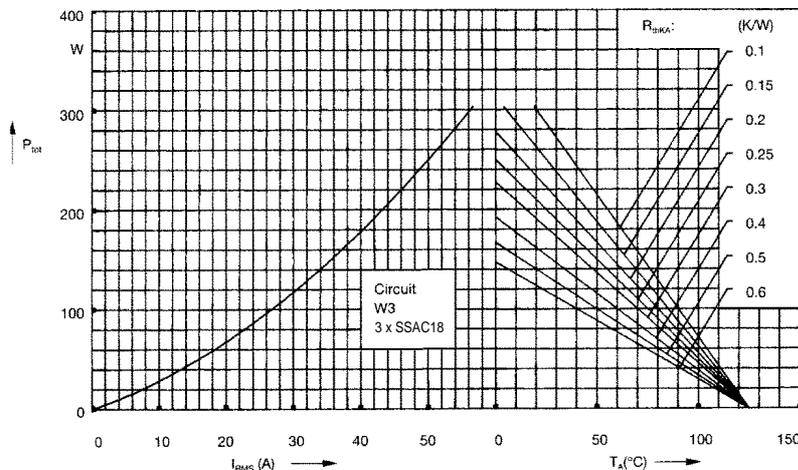


Fig. 7 Three phase AC-controller: Power dissipation versus RMS output current and ambient temperature

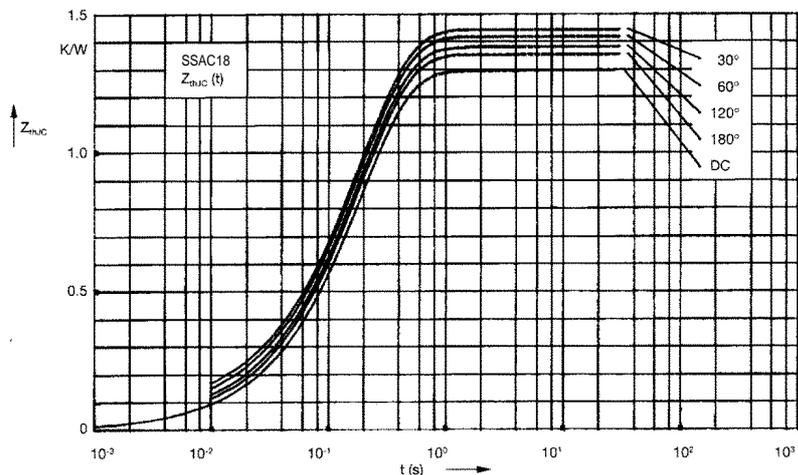


Fig. 8 Transient thermal impedance junction to case (per thyristor)

R_{thJC} for various conduction angles d :

| d | R_{thJC} (K/W) |
|-----------------|------------------|
| DC | 1.3 |
| 180 $^{\circ}C$ | 1.35 |
| 120 $^{\circ}C$ | 1.39 |
| 60 $^{\circ}C$ | 1.42 |
| 30 $^{\circ}C$ | 1.45 |

Constants for Z_{thJC} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|-----|-----------------|-----------|
| 1 | 0.018 | 0.0033 |
| 2 | 0.041 | 0.0216 |
| 3 | 1.241 | 0.191 |

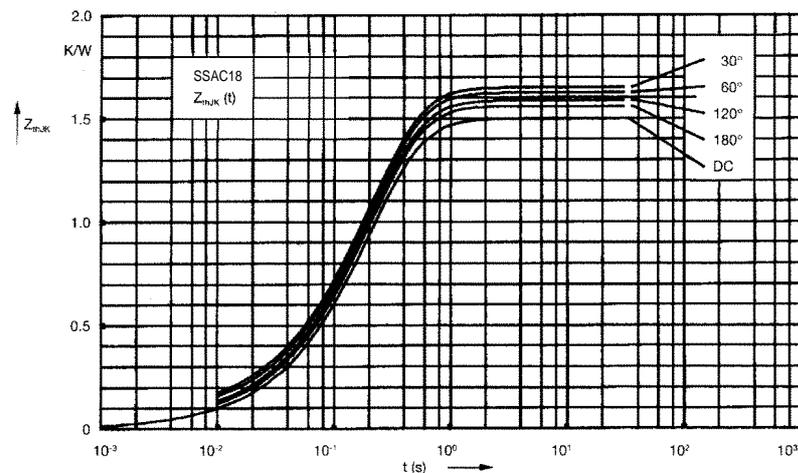


Fig. 9 Transient thermal impedance junction to heatsink (per thyristor)

R_{thJK} for various conduction angles d :

| d | R_{thJK} (K/W) |
|-----------------|------------------|
| DC | 1.5 |
| 180 $^{\circ}C$ | 1.55 |
| 120 $^{\circ}C$ | 1.59 |
| 60 $^{\circ}C$ | 1.62 |
| 30 $^{\circ}C$ | 1.65 |

Constants for Z_{thJK} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|-----|-----------------|-----------|
| 1 | 0.018 | 0.0033 |
| 2 | 0.041 | 0.0216 |
| 3 | 1.241 | 0.191 |
| 4 | 0.2 | 0.46 |